I.	Hits	Search Text	DB	Time stamp
Number				
1	11665	capacitor near8 (substrate or trench or	USPAT	2003/07/08
		groove)		15:29
2	11433	capacitor near8 (substrate or trench or	USPAT	2003/07/08
		groove) and substrate		15:30
3	11433	(capacitor near8 (substrate or trench or	USPAT	2003/07/08
		groove)) and substrate		15:30
4	7104	(capacitor near3 (substrate or trench or	USPAT	2003/07/08
		groove)) and substrate		15:30
5	5709	(capacitor near3 (substrate or trench or	USPAT	2003/07/08
		groove)) and substrate and semiconductor		15:31
6	4725	(capacitor near3 (substrate or trench or	USPAT	2003/07/08
		groove)) and substrate and semiconductor		15:32
		and ("257" or "438")		
7	2134	(capacitor near3 (trench or groove)) and	USPAT	2003/07/08
		substrate and semiconductor and ("257" or		16:19
		"438")		
8	62	(back adj2 side adj2 contact) and	USPAT	2003/07/08
		capacitor		16:25
9	12	(back adj2 side adj2 contact) and	US-PGPUB;	2003/07/08
		capacitor	EPO; JPO;	16:27
			DERWENT;	
			IBM_TDB	//
10	54	capacitor near5 (clock adj line)	USPAT	2003/07/08
				16:33
11	2	capacitor near6 ("input/output" adj pad)	USPAT	2003/07/08
			l	16:43
12	9	capacitor near6 ("input/output" adj pad)	US-PGPUB;	2003/07/08
			EPO; JPO;	16:43
			DERWENT;	
	l		IBM TDB	